

RELIABILITY REPORT FOR MAX5932ESA+

PLASTIC ENCAPSULATED DEVICES

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MAXIM INTEGRATED

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Conclusion

The MAX5932ESA+ successfully meets the quality and reliability standards required of all Maxim Integrated products. In addition, Maxim Integrated's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim Integrated's quality and reliability standards.

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I. Device Description

A. General

The MAX5932 is a fully integrated hot-swap controller for +9V to +80V positive supply rails. The MAX5932 allows for the safe insertion and removal of circuit cards into a live backplane without causing glitches on the backplane power-supply rail. This device is pin and function compatible to LT1641-1. The MAX5932 features a programmable foldback-current limit. If the device remains in current limit for more than a programmable time, the external n-channel MOSFET latches off. Other features include a programmable undervoltage lockout and a programmable output-voltage slew rate through an external n-channel MOSFET. The MAX5932 provides a power-good output (PWRGD) to indicate the status of the output voltage. For a variety of PWRGD/PWRGD-bar, latch/autoretry-fault management, autoretry duty-cycle options, refer to the MAX5933 and MAX5934 data sheets. The MAX5932 operates in the -40°C to +85°C extended temperature range. This device is available in an 8-pin SO package.



II. Manufacturing Information

- A. Description/Function:Positive High-Voltage, Hot-Swap ControllerB. Process:BCD8C. Number of Device Transistors:1565D. Fabrication Location:OregonE. Assembly Location:Philippines, Thailand, Malaysia
- F. Date of Initial Production: April 23, 2004

III. Packaging Information

A. Package Type:	8-pin SOIC (N)
B. Lead Frame:	Copper
C. Lead Finish:	100% matte Tin
D. Die Attach:	Conductive
E. Bondwire:	Au (1 mil dia.)
F. Mold Material:	Epoxy with silica filler
G. Assembly Diagram:	#05-9000-0585
H. Flammability Rating:	Class UL94-V0
 Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C 	Level 1
J. Single Layer Theta Ja:	170°C/W
K. Single Layer Theta Jc:	40°C/W
L. Multi Layer Theta Ja:	128.4°C/W
M. Multi Layer Theta Jc:	36°C/W

IV. Die Information

A. Dimensions:	144 X 85 mils
B. Passivation:	Si_3N_4/SiO_2 (Silicon nitride/ Silicon dioxide)
C. Interconnect:	Al/0.5%Cu with Ti/TiN Barrier
D. Backside Metallization:	None
E. Minimum Metal Width:	3.0 microns (as drawn)
F. Minimum Metal Spacing:	3.0 microns (as drawn)
G. Bondpad Dimensions:	
H. Isolation Dielectric:	SiO ₂
I. Die Separation Method:	Wafer Saw



V. Quality Assurance Information

A. Quality Assurance Contacts:	Richard Aburano (Manager, Reliability Engineering) Don Lipps (Manager, Reliability Engineering) Bryan Preeshl (Vice President of QA)
B. Outgoing Inspection Level:	0.1% for all electrical parameters guaranteed by the Datasheet. 0.1% For all Visual Defects.
C. Observed Outgoing Defect Rate: D. Sampling Plan:	< 50 ppm Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135cC biased (static) life test are shown in Table 1. Using these results, the Failure Rate (λ) is calculated as follows:

$$\lambda = \underbrace{1}_{\text{MTTF}} = \underbrace{1.83}_{\text{192 x 4340 x 48 x 2}} \text{ (Chi square value for MTTF upper limit)}$$

$$\lambda = 22.9 \times 10^{-9}$$

x = 22.9 F.I.T. (60% confidence level @ 25°C)

The following failure rate represents data collected from Maxim Integrated's reliability monitor program. Maxim Integrated performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at http://www.maximintegrated.com/qa/reliability/monitor. Cumulative monitor data for the BCD8 Process results in a FIT Rate of 0.06 @ 25C and 1.08 @ 55C (0.8 eV, 60% UCL)

B. E.S.D. and Latch-Up Testing (lot NFR1BQ001A D/C 0412)

The NP44-1 die type has been found to have all pins able to withstand a HBM transient pulse of +/-1500V per JEDEC JESD22-A114. Latch-Up testing has shown that this device withstands a current of +/-250mA.



Table 1 Reliability Evaluation Test Results

MAX5932ESA+

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	COMMENTS
Static Life Test	(Note 1)				
	Ta = 135°C	DC Parameters	48	0	NFR0BQ001B, D/C 0407
	Biased	& functionality			
	Time = 192 hrs.				

Note 1: Life Test Data may represent plastic DIP qualification lots.